

# QM30TX-H

MEDIUM POWER SWITCHING USE  
INSULATED TYPE

## QM30TX-H



- **IC** Collector current ..... **30A**
- **VCEX** Collector-emitter voltage ..... **600V**
- **hFE** DC current gain ..... **75**
- **Insulated Type**
- **UL Recognized**

Yellow Card No. E80276 (N)

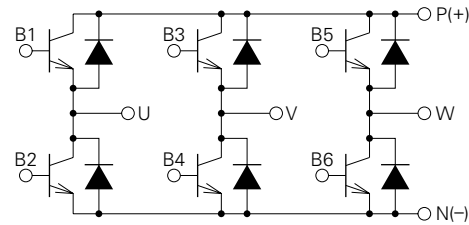
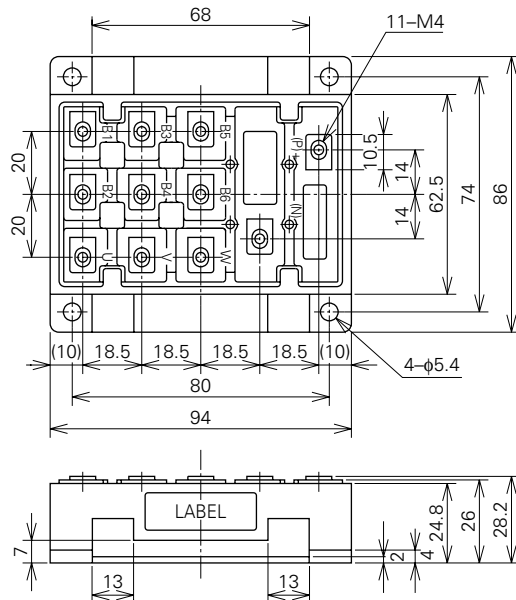
File No. E80271

## APPLICATION

AC motor controllers, UPS, DC motor controllers, NC equipment

## OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



Note: All Transistor Units are Darlington.

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Symbol	Parameter	Conditions	Ratings	Unit
V <sub>CEX</sub> (sus)	Collector-emitter voltage	I <sub>c</sub> =1A, V <sub>EB</sub> =2V	600	V
V <sub>CEX</sub>	Collector-emitter voltage	V <sub>EB</sub> =2V	600	V
V <sub>CBO</sub>	Collector-base voltage	Emitter open	600	V
V <sub>EBO</sub>	Emitter-base voltage	Collector open	7	V
I <sub>c</sub>	Collector current	DC	30	A
-I <sub>c</sub>	Collector reverse current	DC (forward diode current)	30	A
P <sub>c</sub>	Collector dissipation	T <sub>c</sub> =25°C	250	W
I <sub>B</sub>	Base current	DC	1.8	A
-I <sub>CSM</sub>	Surge collector reverse current (forward diode current)	Peak value of one cycle of 60Hz (half wave)	300	A
T <sub>j</sub>	Junction temperature		-40~+150	°C
T <sub>stg</sub>	Storage temperature		-40~+125	°C
V <sub>iso</sub>	Isolation voltage	Charged part to case, AC for 1 minute	2500	V
—	Mounting torque	Main terminal screw M4	0.98~1.47	N·m
			10~15	kg·cm
		Mounting screw M5	1.47~1.96	N·m
			15~20	kg·cm
—	Weight	Typical value	520	g

ELECTRICAL CHARACTERISTICS (T<sub>j</sub>=25°C, unless otherwise noted)

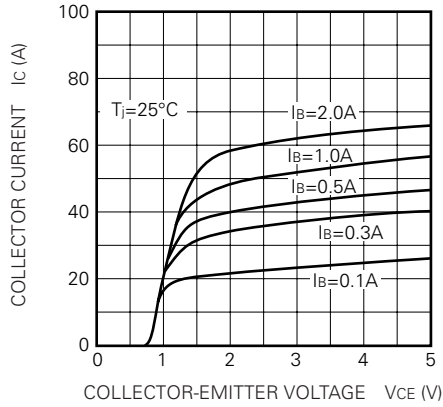
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I <sub>CEX</sub>	Collector cutoff current	V <sub>CE</sub> =600V, V <sub>EB</sub> =2V	—	—	1.0	mA
I <sub>CBO</sub>	Collector cutoff current	V <sub>CB</sub> =600V, Emitter open	—	—	1.0	mA
I <sub>EBO</sub>	Emitter cutoff current	V <sub>EB</sub> =7V	—	—	200	mA
V <sub>CE</sub> (sat)	Collector-emitter saturation voltage	I <sub>c</sub> =30A, I <sub>B</sub> =0.4A	—	—	2.0	V
V <sub>BE</sub> (sat)	Base-emitter saturation voltage		—	—	2.5	V
-V <sub>CEO</sub>	Collector-emitter reverse voltage	-I <sub>c</sub> =30A (diode forward voltage)	—	—	1.85	V
h <sub>FE</sub>	DC current gain	I <sub>c</sub> =30A, V <sub>CE</sub> =2V/5V	75/100	—	—	—
t <sub>on</sub>	Switching time	V <sub>CC</sub> =300V, I <sub>c</sub> =30A, I <sub>B1</sub> =-I <sub>B2</sub> =0.6A	—	—	1.5	μs
t <sub>s</sub>			—	—	12	μs
t <sub>f</sub>			—	—	3.0	μs
R <sub>th</sub> (j-c) Q	Thermal resistance (junction to case)	Transistor part (per 1/6 module)	—	—	0.5	°C/W
R <sub>th</sub> (j-c) R		Diode part (per 1/6 module)	—	—	2.0	°C/W
R <sub>th</sub> (c-f)	Contact thermal resistance (case to fin)	Conductive grease applied (per 1/6 module)	—	—	0.2	°C/W

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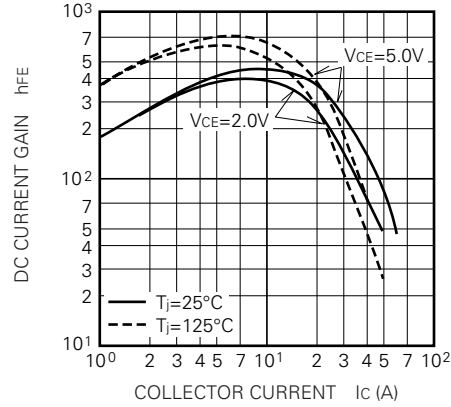
MEDIUM POWER SWITCHING USE  
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## PERFORMANCE CURVES

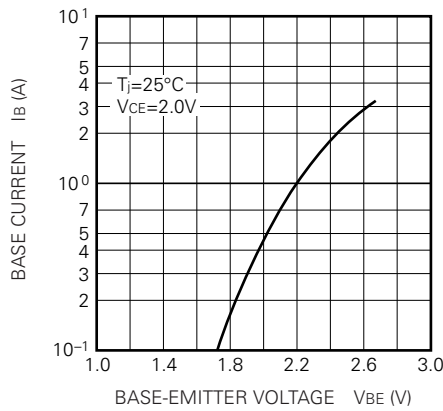
COMMON EMITTER OUTPUT CHARACTERISTICS (TYPICAL)



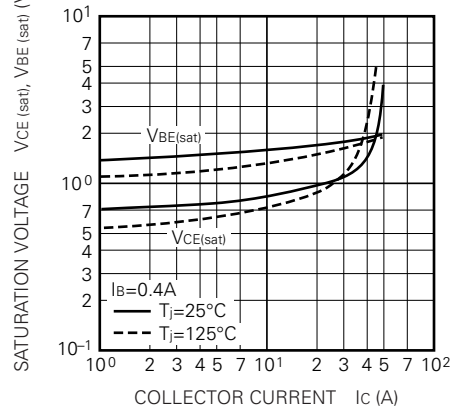
DC CURRENT GAIN VS. COLLECTOR CURRENT (TYPICAL)



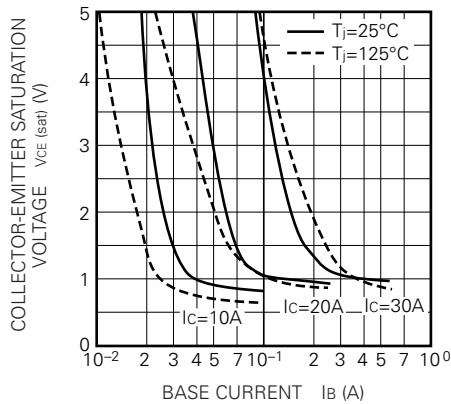
COMMON EMITTER INPUT CHARACTERISTIC (TYPICAL)



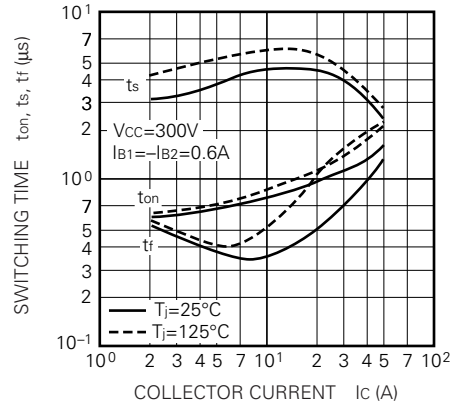
SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



COLLECTOR-EMITTER SATURATION VOLTAGE (TYPICAL)



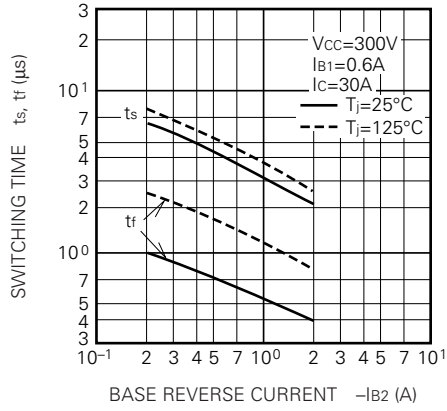
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



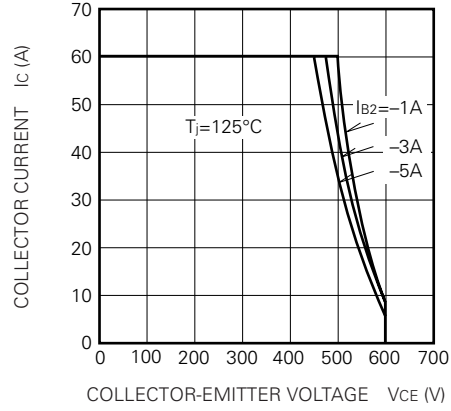
**QM30TX-H**

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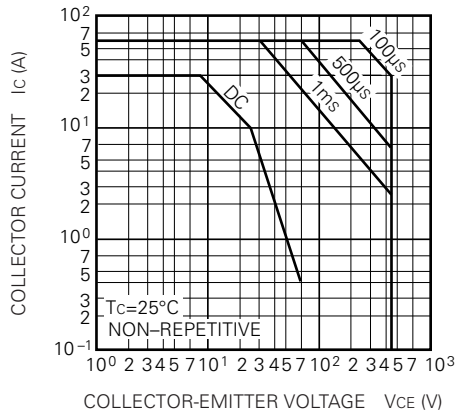
**SWITCHING TIME VS. BASE CURRENT (TYPICAL)**



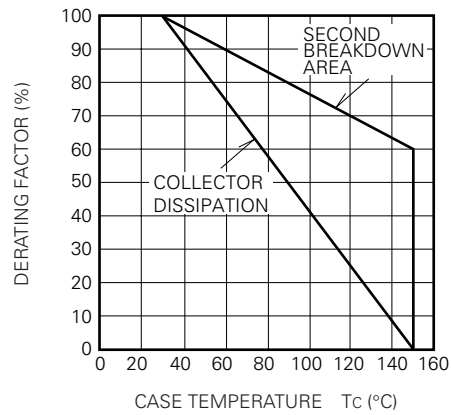
**REVERSE BIAS SAFE OPERATING AREA**



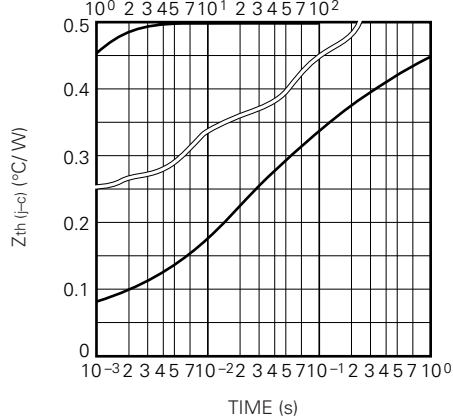
**FORWARD BIAS SAFE OPERATING AREA**



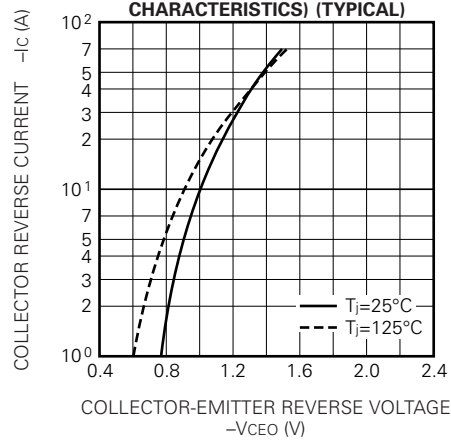
**DERATING FACTOR OF F. B. S. O. A.**



**TRANSIENT THERMAL IMPEDANCE CHARACTERISTIC (TRANSISTOR)**



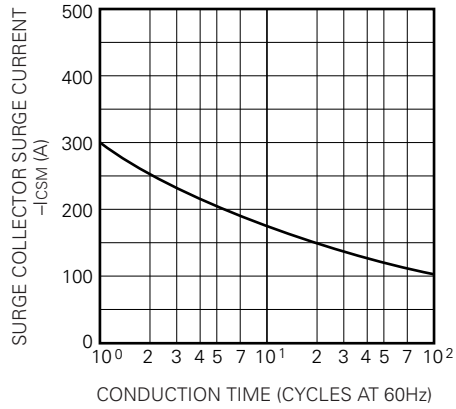
**REVERSE COLLECTOR CURRENT VS. COLLECTOR-EMITTER REVERSE VOLTAGE (DIODE FORWARD CHARACTERISTICS) (TYPICAL)**



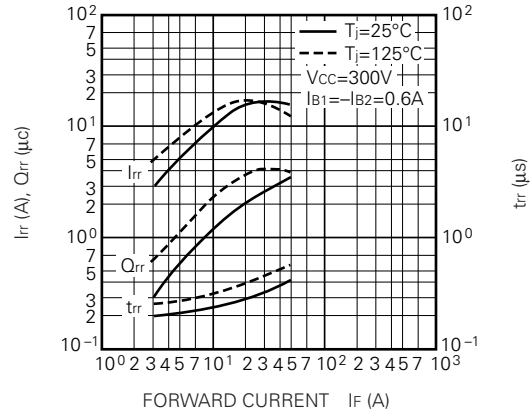
# QM30TX-H

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**RATED SURGE COLLECTOR REVERSE CURRENT  
(DIODE FORWARD SURGE CURRENT)**



**REVERSE RECOVERY CHARACTERISTICS  
OF FREE-WHEEL DIODE (TYPICAL)**



**TRANSIENT THERMAL IMPEDANCE  
CHARACTERISTIC (DIODE)**

